

# NX5501 Series

# 1 550 nm FOR FTTH InGaAsP MQW-FP LASER DIODE

#### **★** DESCRIPTION

The NX5501 Series is a 1 550 nm Multiple Quantum Well (MQW) structured Fabry-Perot (FP) laser diode with InGaAs monitor PIN-PD.

#### **★** APPLICATION

• FTTH (Fiber To The Home)

#### **FEATURES**

Optical output power
 Po = 5.0 mW
 Low threshold current
 Ith = 8 mA
 pd = 0.3 W/A
 Wide operating temperature range
 Tc = -40 to +85°C

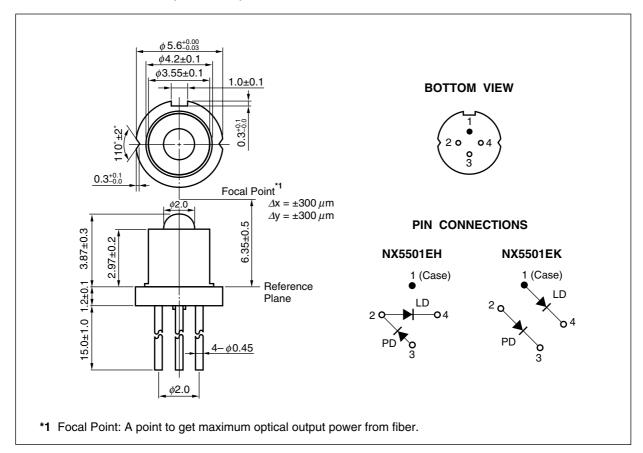
• InGaAs monitor PIN-PD

• CAN package  $\phi$  5.6 mm



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# **★ PACKAGE DIMENSIONS (UNIT: mm)**



# **★ ORDERING INFORMATION**

Part Number	Package	Pin Connections
NX5501EH	4-pin CAN with ball lens cap	2 O O O O O O O O O O O O O O O O O O O
NX5501EK		20 LD 4 PD 3

Remarks 1. The color of ball lens cap might be observed differently from our can package products.

2. The hermetic test will be performed as AQL 1.0%.

# **ABSOLUTE MAXIMUM RATINGS**

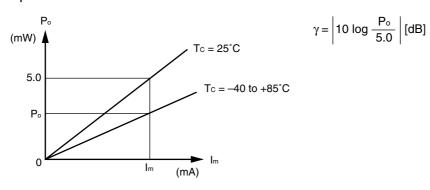
Parameter	Symbol	Ratings	Unit
Optical Output Power	Po	10	mW
Forward Current of LD	lF	150	mA
Reverse Voltage of LD	VR	2.0	٧
Forward Current of PD	lF	10	mA
Reverse Voltage of PD	VR	20	٧
Operating Case Temperature	Tc	-40 to +85	°C
Storage Temperature	T <sub>stg</sub>	-40 to +85	°C
Assembly Temperature	Tasb	150 (15 Hr)	°C
Lead Soldering Temperature	Tsld	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

\*

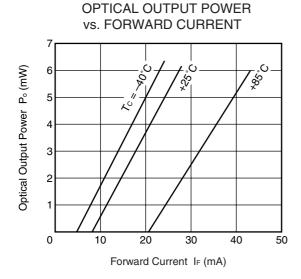
# ELECTRO-OPTICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating Voltage	Vop	$P_0 = 5.0 \text{ mW}, T_C = -40 \text{ to } +85^{\circ}\text{C}$		1.1	1.5	V
Threshold Current	Ith			8	20	mA
		Tc = 85°C		20	40	
Threshold Output Power	Pth	$T_{C} = -40 \text{ to } +85^{\circ}\text{C}, I_{F} = I_{th}$		100	200	μW
Differential Efficiency	$\eta_{ extsf{d}}$		0.15	0.3		W/A
Temperature Dependence of Differential Efficiency	$\varDelta\eta$ d	$\Delta \eta_{\rm d} = 10 \log \frac{\eta_{\rm d}  (@ 85^{\circ} \text{C})}{\eta_{\rm d}  (@ 25^{\circ} \text{C})}$	-3.0	-1.5		dB
Center Wavelength	λο	$P_{\circ} = 5.0$ mW, RMS (–20 dB), $T_{\rm C} = -40$ to +85°C	1 480		1 580	nm
Temperature Dependence of Center Wavelength	Δλ/ΔΤ	Tc = -40 to +85°C		0.5		nm/°C
Spectral Width	σ	$P_{\circ} = 5.0$ mW, RMS (–20 dB), $T_{\rm C} = -40$ to +85°C		1.5	3.0	nm
Rise Time	tr	10-90%			0.7	ns
Fall Time	tf	90-10%			0.7	ns
Monitor Current	lm	V <sub>R</sub> = 5 V, P <sub>o</sub> = 5.0 mW	200		800	μΑ
Monitor Dark Current	ΙD	V <sub>R</sub> = 5 V		0.1	10	nA
		$V_R = 5 \text{ V}, T_C = -40 \text{ to } +85^{\circ}\text{C}$			500	
Monitor PD Terminal Capacitance	Ct	V <sub>R</sub> = 5 V, f = 1 MHz		6	20	pF
Tracking Error <sup>*1</sup>	γ	$I_{m} = const.$ (@ $P_{o} = 5.0$ mW, $T_{C} = 25^{\circ}C$ ), $T_{C} = -40$ to $+85^{\circ}C$	-1.0		1.0	dB

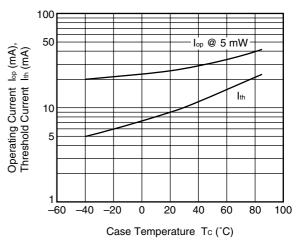
# \*1 Tracking Error: $\gamma$



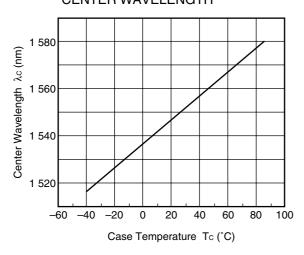
## **★** TYPICAL CHARACTERISTICS (Tc = -40 to +85°C, unless otherwise specified)



OPERATING CURRENT AND THRESHOLD CURRENT vs. CASE TEMPERATURE

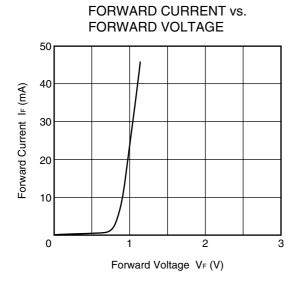


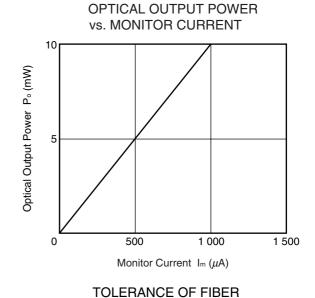
# TEMPERATURE DEPENDENCE OF CENTER WAVELENGTH

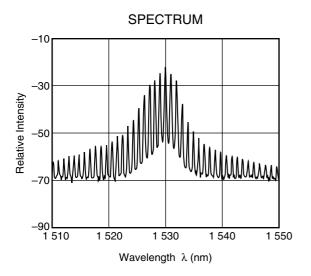


**Remark** The graphs indicate nominal characteristics.

## TYPICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)







0.8 Otical Output Power from Fiber Pr (mW) 0.7 P<sub>o</sub> = 5.0 mW 0.6 0.5 0.4 0.3

6.2

Z-Axis Tolerance Z (mm)

6.4

6.6

0.2 0.1

0.0**L** 5.8

6.0

COUPLING DISTANCE (Z)

**Remark** The graphs indicate nominal characteristics.



## **REFERENCE**

Document Name	Document No.	
OPTICAL SEMICONDUCTOR DEVICES FOR FIBEROPTIC COMMUNICATIONS SELECTION GUIDE	PL10161E	
Opto-Electronics Devices Pamphlet	PX10160E	

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M8E 00.4-0110



#### SAFETY INFORMATION ON THIS PRODUCT



#### **SEMICONDUCTOR LASER**



AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

Warning Laser Beam	A laser beam is emitted from this diode during operation.  The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.
	Do not look directly into the laser beam.
	Avoid exposure to the laser beam, any reflected or collimated beam.
Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	Do not lick the product or in any way allow it to enter the mouth.

#### ▶ For further information, please contact

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